

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

| Supplier   |                              | User Part Number   |                       |           |            |           |  |   |
|--|------------------------------|--|-----------------------|-----------|------------|-----------|--|---|
| Nexperia B.V.<br>Name of Laboratory<br>Assembly reliability labs<br>Based on AEC-Q101 Test |                              | PIMN31 Part Description                                    |                       |           |            |           |  |   |
|  |                              |  |                       |           |            |           |  | Nexperia DHAM Small Signal Bipolar Transistor SMD package |
|  |                              | Test Conditions  | Duration              | # Lots    | # Quantity | # Rejects |  |   |
|  |                              |  | TEST                  |           |            |           |  |   |
|  |                              |  | Pre- and Post-Stress  |           |            |           |  |   |
| # E1   | Electrical Test              | Tamb = 25 °C   | N/A                   | see below | all parts  | see below |  |   |
|  |                              | JESD22-A113  |                       |           |            |           |  |   |
|  |                              | Bake Tamb = 125 °C   | 24 hours              |           |            |           |  |   |
|  | <b>PC</b><br>Preconditioning | Soak Tamb = 85 °C, RH = 85%<br>Reflow soldering            | 168 hours<br>3 cycles | 0.40      | 64470      |           |  |   |
| # A1   | Freconditioning              | 5  | JUYLIES               | 849       | 61170      | 0         |  |   |
|  |                              | MIL-STD-750-1  |                       |           |            |           |  |   |
|  | HTRB                         | M1039 Method A   |                       |           |            |           |  |   |
| # B1   | Bias                         | Tj = Tjmax, Vr = $100\%$ of max. datasheet reverse voltage | 1000 hours            | 202       | 16160      | 0         |  |   |
| # B1   | 5103                         | Teverse voltage  | 1000 nours            | 202       | 10100      | 0         |  |   |
|  | тс                           | JESD22-A104  |                       |           |            |           |  |   |
| # A4   | Temperature Cycling          | -65 °C to Tjmax, not to exceed 150°C                       | 1000 cycles           | 171       | 13680      | 0         |  |   |
|  |                              | JESD22-A102  |                       |           |            |           |  |   |
|  | AC                           | Tamb = 121 °C, RH = 100 %                                  |                       |           |            |           |  |   |
| # A3 alt   | Autoclave                    | Pressure = 205 kPa (29.7 psia)                             | 96 hours              | 173       | 13840      | 0         |  |   |
|  |                              |  |                       |           |            |           |  |   |
|  | H3TRB                        | JESD22-A101  |                       |           |            |           |  |   |
|  | High Humidity High           | Tamb = 85 °C, RH = 85%, VR = 80 % of                       |                       |           |            |           |  |   |
| # A2 alt   | Temperature Reverse Bias     | rated reverse voltage <sup>[1]</sup>                       | 1000 hours            | 173       | 13840      | 0         |  |   |
|  |                              | MIL-STD-750 Method 1037                                    |                       |           |            |           |  |   |
|  | IOL                          | ton = toff, devices powered to insure $\Delta Tj$ =        |                       |           |            |           |  |   |
| # A5   | Intermittent Operating Life  | 100 °C for 15000 cycles                                    | 1000 hours            | 197       | 15760      | 0         |  |   |
|  |                              |  |                       |           |            |           |  |   |
|  | RSH                          | JESD22-A111  |                       |           |            |           |  |   |
| # C8   | Resistance to Solder Heat    | 260 °C ± 5 °C  | 10 s                  | 135       | 4050       | 0         |  |   |
|  | SD                           |  |                       |           |            |           |  |   |
| # C10  | Solderability                | J-STD-002  |                       | 342       | 3420       | 0         |  |   |

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

| Wafer Fab        | Technology                         | Quantity | Rejects | Failure Rate (FIT) | MTTF (hrs) |
|------------------|------------------------------------|----------|---------|--------------------|------------|
| Nexperia<br>DHAM | Small Signal Bipolar<br>Transistor | 16160    | 0       | 0.26               | 3.81E+09   |

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